

ChipSESD

Silicon ESD Protector
Overvoltage Protection Device

PRODUCT: SESD0201P1BN-0400-090

DOCUMENT: SCD27763 REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 1 of 5

Specification Status: Released

BENEFITS

- Silicon ESD device in an EIA-0201 size rectangular passive component SMT package
- Standard PCB assembly and rework processes
- Bi-directional operation allows placement on PCB without orientation constraint
- Appropriate for ESD protection in space-constrained portable electronics and mobile handsets
- Suitable for +5V operating voltage applications
- Helps protect electronic circuits against damage from Electrostatic Discharge (ESD) events
- Assist equipment to pass IEC61000-4-2, level 4 testing
- RoHS compliant and Halogen Free

FEATURES

- Input capacitance 4pF (typ)
- Low leakage current 1.0µA (max)
- Low working reverse voltage 6.0V (max)
- ESD maximum rating per IEC61000-4-2 standard
 - o ± 10kV contact discharge (1)
 - o ± 16kV air discharge
- Capable of withstanding numerous ESD strikes
- Small package size: 0.60mm x 0.30mm (typ)
- Low package height: 0.30mm (typ)

APPLICATIONS

- Cellular phones and portable electronics
- Digital cameras and camcorders
- USB 2.0 and computer I/O ports
- Keypads, pushbuttons, low voltage DC lines, speakers, headphones, microphones
- Applications requiring high ESD performance

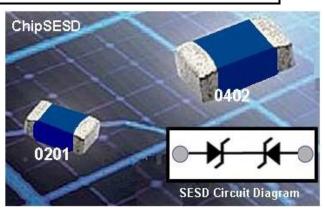
RoHS Compliant ELV Compliant Halogen Free *



Directive 2002/95/EC Compliant

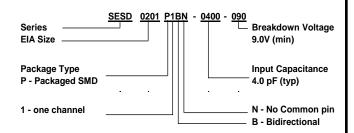


* Halogen Free refers to: Br≤900ppm, Cl≤900ppm, Br+Cl≤1500ppm Terminal finish: 100% Matte Tin (Sn)



PART NUMBERING

MATERIALS INFORMATION





ChipSESD Silicon ESD Protector Overvoltage Protection Device

PRODUCT: SESD0201P1BN-0400-090

DOCUMENT: SCD27763

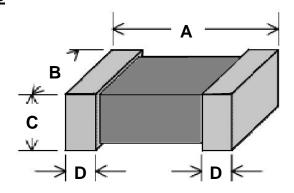
REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 2 of 5

Device Characteristics @ T = 25°C	Min	Тур	Max	Unit
Input Capacitance @ V _r = 0V, f = 1MHz		4.0	5.0	pF
Working Reverse Voltage (peak) - V _{RWM}			6.0	V
Breakdown Voltage – V _{br} @ I _t = 1mA ⁽²⁾	9.0	11.0		V
Leakage current @ V _{RWM} = 6.0V			1.0	μA
Clamping Voltage @ Ipp=2A, tp=(8/20µs)	0μs)		±12.0	V
ESD contact discharge per IEC61000-4-2 standard (1)			±10	kV
ESD air discharge per IEC61000-4-2 standard			±16	kV
Operating (T _{junction}) and Storage Temperature Range	Range -40 to +125			°C

^{(1) 10}kV @ ± 50 pulses under IEC61000-4-2; 8kV @ 1,000 pulses under IEC61000-4-2

DEVICE DIMENSIONS

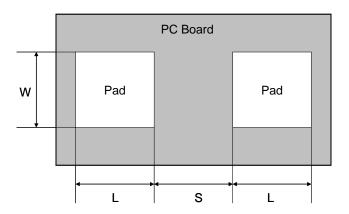


Drawing Not To Scale

Typical	А	В	С	D
mm	0.60 ± 0.05	0.30 ± 0.05	0.30 ± 0.05	0.21 ± 0.07
mils*	23.62 ± 2.0	11.81 ± 2.0	11.81 ± 2.0	8.27 ± 2.8

^{*} Round off approximation

RECOMMENDED LANDING PATTERN:



⁽²⁾ V_{br} is measured at test current I_t



ChipSESD

Silicon ESD Protector Overvoltage Protection Device

PRODUCT: SESD0201P1BN-0400-090

DOCUMENT: SCD27763 REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 3 of 5

	L	S	W
mm	0.28 ± 0.01	0.19 ± 0.01	0.30 ± 0.01
mils*	11.0 ± 0.4	7.5 ± 0.4	11.8 ± 0.4

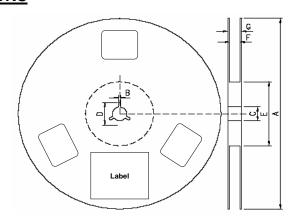
^{*} Round off approximation

- ullet Recommended solder thickness: 150 to 200 um
- Recommended rework procedure:
 - Soldering iron tip temperature should be less than 350°C
 - Apply iron tip to solder for less than 5 seconds
 - o Do not apply solder iron tip to the body of this product directly

PACKAGING

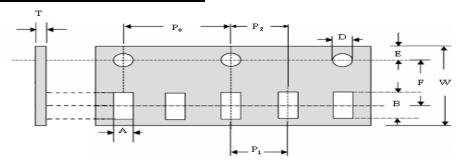
Packaging	Tape & Reel	Standard Box	
SESD0201P1BN-0400-090	15,000	75,000	

REEL DIMENSIONS



Dimension	Α	В	С	D	E	F	G
(mm)	178.0 ± 2.0	2.0 ± 0.5	13.0 ± 0.5	21.0 ± 0.8	62.0 ± 1.5	9.0 ± 0.5	13.0 ± 1.0

CARRIER TAPE DIMENSIONS





ChipSESD Silicon ESD Protector Overvoltage Protection Device

PRODUCT: SESD0201P1BN-0400-090

DOCUMENT: SCD27763 REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 4 of 5

Dimension	Α	В	D	E	F	W
(mm)	0.39 ± 0.03	0.69 ± 0.03	1.55 ± 0.05	1.75 ± 0.05	3.5 ± 0.05	8.0 ± 0.1

Dimension	P_0	P ₁	P ₂	Т	
(mm)	4.0 ± 0.1	2.0 ± 0.05	2.0 ± 0.05	0.42 ± 0.03	

FIGURE 1: TYPICAL IV CURVE

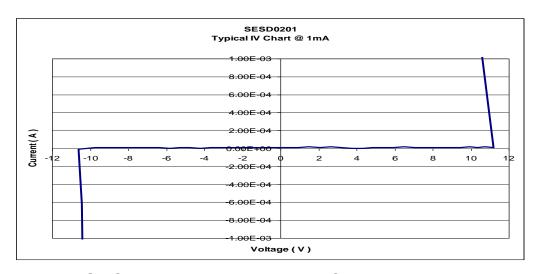
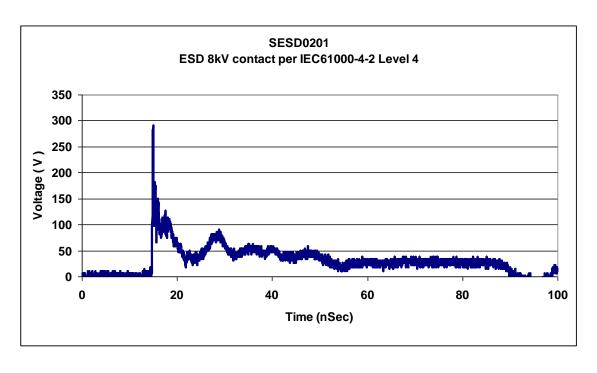


FIGURE 2: ESD CLAMPING VOLTAGE - 8kV Contact





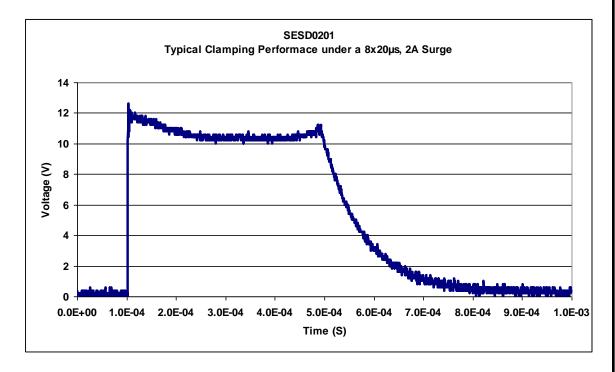
ChipSESD Silicon ESD Protector Overvoltage Protection Device

PRODUCT: SESD0201P1BN-0400-090

DOCUMENT: SCD27763 REV LETTER: B

REV DATE: JULY 26, 2016 PAGE NO.: Page 5 of 5

FIGURE 3: ESD CLAMPING VOLTAGE - 8x20µs, 2A Surge



Littlefuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littlefuse product documentation. Warranties granted by Littlefuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littlefuse documentation. Littlefuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littlefuse as set forth in applicable Littlefuse documentation. The sale and use of Littlefuse products is subject to Littlefuse Terms and Conditions of Sale, unless otherwise agreed by Littlefuse.